

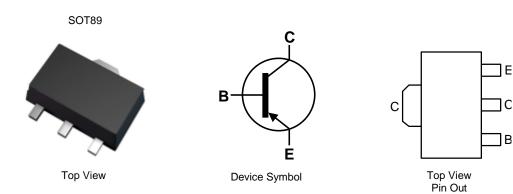
#### **400V PNP HIGH VOLTAGE TRANSISTOR IN SOT89**

#### **Features**

- BV<sub>CEO</sub> > -400V
- I<sub>C</sub> = -200mA High Continuous Current
- I<sub>CM</sub> = -500mA Peak Pulse Current
- Excellent h<sub>FE</sub> Characteristics up to -100mA
- Low Saturation Voltage V<sub>CE(sat)</sub> < -200mV @ -20mA</li>
- Complementary NPN Type: FCX458
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.05 grams (Approximate)



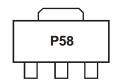
## Ordering Information (Note 4)

h						
	Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	FCX558TA	AEC-Q101	P58	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

#### **Marking Information**



P58 = Product Type Marking Code



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	-400	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-400	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-200	mA
Peak Pulse Current	I <sub>CM</sub>	-500	mA

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)	P <sub>D</sub>	0.7	W	
Bower Discination	(Note 6)		1.0		
Power Dissipation	(Note 7)		1.5		
	(Note 8)		2.0		
	(Note 5)	R <sub>ӨЈА</sub>	178	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)		125		
Thermal Resistance, Junction to Ambient Air	(Note 7)		83		
	(Note 8)		60		
Thermal Resistance, Junction to Lead (Note 9)		$R_{ heta JL}$	22		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C		

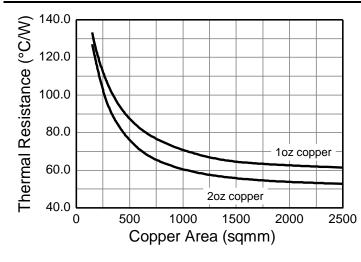
#### ESD Ratings (Note 10)

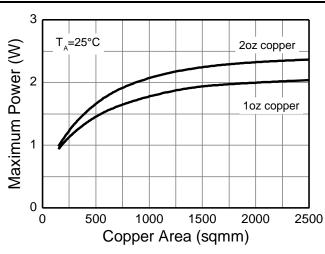
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the exposed collector pad on minimum recommended pad layout (MRP) 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted with the exposed collector pad on 15mm x 15mm 1oz copper.
- 7. Same as Note 5, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.
- 8. Same as Note 5, except the device is mounted with the exposed collector pad on 50mm x 50mm 1oz copper.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

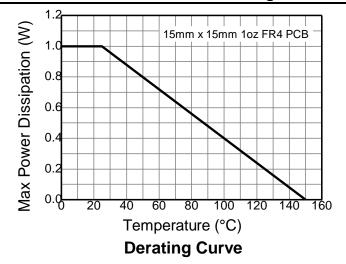
#### **Thermal Characteristics and Derating Information**

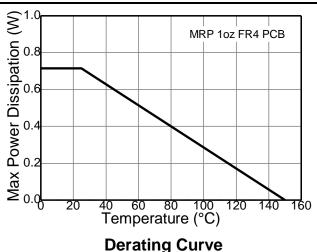


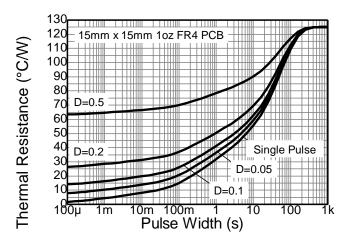


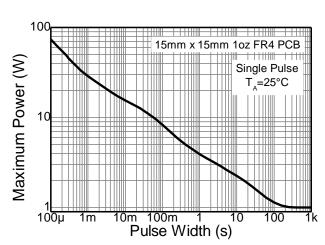


## Thermal Characteristics and Derating Information (cont.)



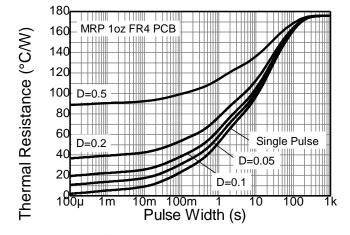


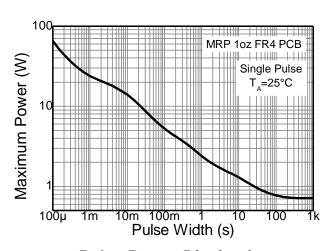




**Transient Thermal Impedance** 

**Pulse Power Dissipation** 





**Transient Thermal Impedance** 

**Pulse Power Dissipation** 





## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

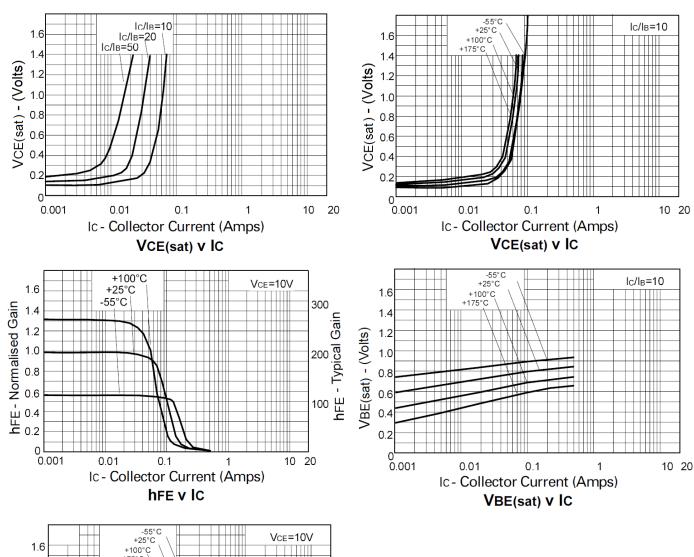
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-400	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-400	-	-	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	=	<1	-100	nA	V <sub>CB</sub> = -320V
Emitter Cutoff Current	I <sub>EBO</sub>	=	<1	-100	nA	$V_{EB} = -5V$
Emitter Cutoff Current	I <sub>CES</sub>	=	<1	-100	nA	V <sub>CES</sub> = -320V
DC Current Transfer Static Ratio (Note 11)	h <sub>FE</sub>	100 100 15	- - -	- 300 -	-	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -10V I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>		-	-0.2 -0.5	V	I <sub>C</sub> = -20mA, I <sub>B</sub> = -2mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -6mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	-	-	-0.9	V	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
Base-Emitter Turn-on Voltage (Note 11)	V <sub>BE(on)</sub>	=	-	-0.9	V	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
Transitional Frequency	f⊤	50	-	-	MHz	$I_E = -10 \text{mA}, V_{CE} = -20 \text{V}$ f = 20 MHz
Output Capacitance	$C_{obo}$	-	-	5	pF	$V_{CB} = -20V, f = 1MHz,$
Switching Times	t <sub>on</sub> t <sub>off</sub>	_	95 1600	-	nS	$I_C = -50$ mA, $V_C = -100$ V $I_{B1} = -5$ mA, $I_{B2} = -10$ mA

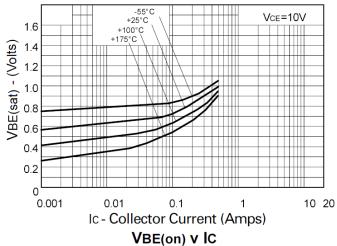
Note:

11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

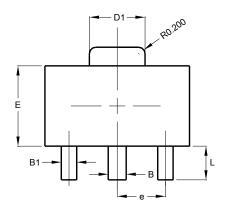


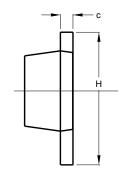


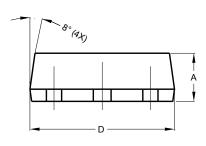


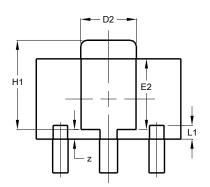
## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.





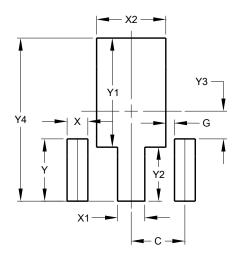




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
C	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	1.50			
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.427 REF				
Z	0.30 REF				
All Dimensions in mm					

#### **Suggested Pad Layout**

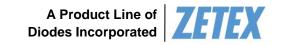
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	value		
Dimensions	(in mm)		
С	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





December 2014

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